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Vishay Semiconductors

COMPLIANT HALOGEN

**FREE** 

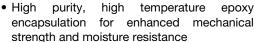
# High Performance Schottky Rectifier, 2 x 15 A

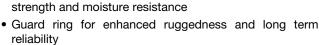


PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	2 x 15 A						
V <sub>R</sub>	35 V, 45 V						
V <sub>F</sub> at I <sub>F</sub>	See Electrical table						
I <sub>RM</sub> max.	40 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
E <sub>AS</sub>	16 mJ						
Package	3L TO-220AB						
Circuit configuration	Common cathode						

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation





- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>F(AV)</sub>	Rectangular waveform (per device)	30	Α					
V <sub>RRM</sub>		35/45	V					
I <sub>FRM</sub>	T <sub>C</sub> = 130 °C (per leg)	30	^					
I <sub>FSM</sub>	t <sub>p</sub> = 5 µs sine	1060	Α					
V <sub>F</sub>	30 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.73	V					
T <sub>J</sub>	Range	-65 to +150	°C					

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-MBR2535CT-M3 VS-MBR2545CT-M3 UNIT								
Maximum DC reverse voltage	$V_R$	35	45	W				
Maximum working peak reverse voltage	$V_{RWM}$	35	45	ľ				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum average forward per leg		T = 120 °C reted V		15				
current per device	I <sub>F(AV)</sub>	T <sub>C</sub> = 130 °C, rated V <sub>R</sub>		30				
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 130 °C					
Non-repetitive peak surge current	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	А			
	1 0141	Surge applied at rated load conditions halfwave, single phase, 60 Hz		150				
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25$ °C, $I_{AS} = 2$ A, $L = 8$ mH		16	mJ			
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		2	Α			



# **VS-MBR2535CT-M3, VS-MBR2545CT-M3**

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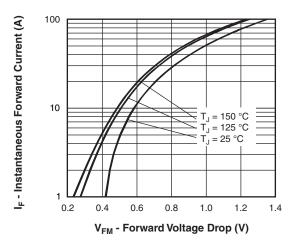
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum famuard valtage drep	V (1)	30 A	T <sub>J</sub> = 25 °C	0.82	V			
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	30 A	T <sub>J</sub> = 125 °C	0.73	V			
Maximum instantaneous volcase surrent	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Dated DC valtage	0.2	m۸			
Maximum instantaneous reverse current	'RM (*)	T <sub>J</sub> = 125 °C	Rated DC voltage	40	mA			
Threshold voltage	V <sub>F(TO)</sub>	T <sub>.I</sub> = T <sub>.I</sub> maximum	T T					
Forward slope resistance	r <sub>t</sub>	ıj = ıjınaxımum	12.3	mΩ				
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range	700	pF				
Typical series inductance	L <sub>S</sub>	Measured from top of termina	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ		-65 to +150	°C				
Maximum storage temperature range	T <sub>Stg</sub>		-65 to +175					
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	1.5	°C/W				
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	C/ <b>VV</b>				
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Mounting torque minim	num	Non-lubricated threads	6 (5)	kgf ⋅ cm				
Mounting torque maxim	num	Non-iublicated tilleaus	12 (10)	(lbf · in)				
Marking daying		Coop obdo 21 TO 220AB	MBR2	535CT				
Marking device		Case style 3L TO-220AB	MBR2	MBR2545CT				

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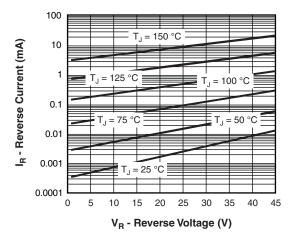


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

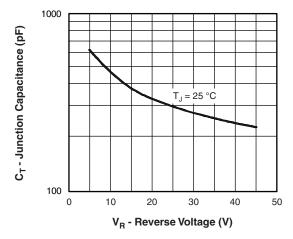


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

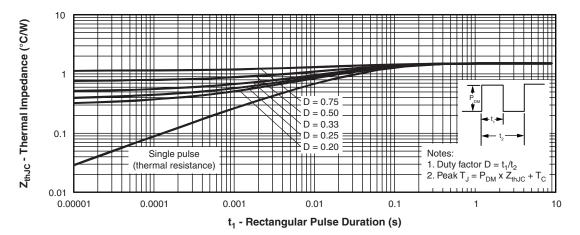


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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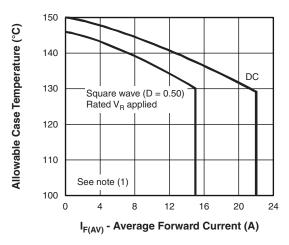


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

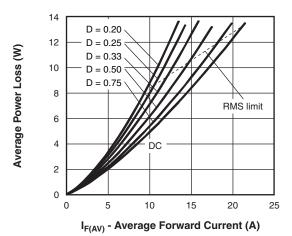


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

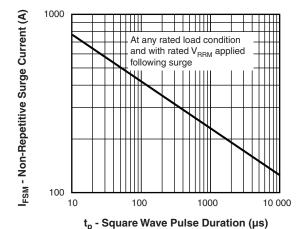


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

### Note

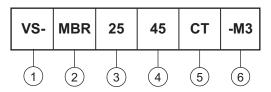
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; \ I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$ 

# **VS-MBR2535CT-M3, VS-MBR2545CT-M3**

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### **ORDERING INFORMATION TABLE**

**Device code** 



- Vishay Semiconductors product

- Schottky MBR series

Current rating (30 A)

35 = 35 V 45 = 45 V

5 - CT = essential part number

6 - Environmental digit
-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBR2535CT-M3	50	1000	Antistatic plastic tube						
VS-MBR2545CT-M3	50	1000	Antistatic plastic tube						

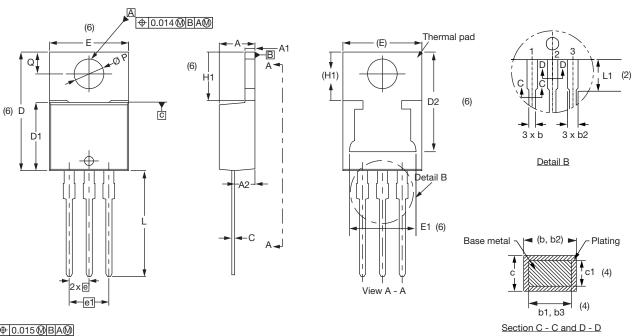
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						



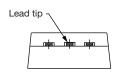
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## **3L TO-220AB**

### **DIMENSIONS** in millimeters and inches



### **⊕** 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INCHES		NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

### **Notes**

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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